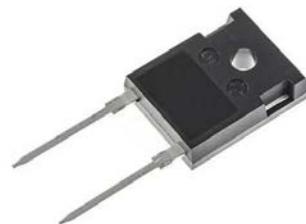




Features

- 1.2kV Schottky Rectifier
- Zero Reverse Recovery Current
- High-Frequency Operation
- Temperature-Independent Switching
- Extremely Fast Switching
- Positive Temperature Coefficient on V_F
- Increased Creepage/Clearance Distance



TO247-2L
Package

Benefits

- Replace Bipolar with Unipolar Rectifiers
- Essentially No Switching Losses
- Higher Efficiency
- Reduction of Heat Sink Requirements
- Parallel Devices Without Thermal Runaway



Applications

- Switch Mode Power Supplies (SMPS)
- Boost diodes in PFC or DC/DC stages
- Free Wheeling Diodes in Inverter stages
- AC/DC converters



Part Number	Package	Qty(PCS)
HWN101200WQ	TO247-2L	30

Maximum Ratings ($T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Unit	Test Conditions	Note
V_{RRM}	Repetitive Peak Reverse Voltage	1200	V		
V_{RSM}	Surge Peak Reverse Voltage	1300	V		
V_R	DC Peak Reverse Voltage	1200	V		
I_F	Continuous Forward Current	31.5 15 10	A	$T_c=25^\circ\text{C}$ $T_c=135^\circ\text{C}$ $T_c=155^\circ\text{C}$	Fig. 3
I_{FRM}	Repetitive Peak Forward Surge Current	46 30	A	$T_c=25^\circ\text{C}, t_p=10\text{ ms, Half Sine Pulse}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms, Half Sine Pulse}$	
I_{FSM}	Non-Repetitive Forward Surge Current	67 59	A	$T_c=25^\circ\text{C}, t_p=10\text{ ms, Half Sine Pulse}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms, Half Sine Pulse}$	Fig. 8
$I_{F,Max}$	Non-Repetitive Peak Forward Current	750 620	A	$T_c=25^\circ\text{C}, t_p=10\text{ ms, Pulse}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms, Pulse}$	Fig. 8
P_{tot}	Power Dissipation	153 66	W	$T_c=25^\circ\text{C}$ $T_c=110^\circ\text{C}$	Fig. 4
dV/dt	Diode dV/dt ruggedness	200	V/ns	$V_R=0-960\text{V}$	
$\int i^2 dt$	$i^2 t$ value	22.5 17.5	A ² s	$T_c=25^\circ\text{C}, t_p=10\text{ ms}$ $T_c=110^\circ\text{C}, t_p=10\text{ ms}$	
T_J, T_{stg}	Operating Junction and Storage Temperature	-55 to +175	°C		
	TO-247 Mounting Torque	1 8.8	Nm lbf-in	M3 Screw 6-32 Screw	



Electrical Characteristics

Symbol	Parameter	Typ.	Max.	Unit	Test Conditions	Note
V_F	Forward Voltage	1.5 2.2	1.8 3	V	$I_F = 10 \text{ A}$ $T_J = 25^\circ\text{C}$ $I_F = 10 \text{ A}$ $T_J = 175^\circ\text{C}$	Fig. 1
I_R	Reverse Current	30 55	250 350	μA	$V_R = 1200 \text{ V}$ $T_J = 25^\circ\text{C}$ $V_R = 1200 \text{ V}$ $T_J = 175^\circ\text{C}$	Fig. 2
Q_C	Total Capacitive Charge	52		nC	$V_R = 800 \text{ V}$, $I_F = 10\text{A}$ $dI/dt = 200 \text{ A}/\mu\text{s}$ $T_J = 25^\circ\text{C}$	Fig. 5
C	Total Capacitance	754 45 38		pF	$V_R = 0 \text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1 \text{ MHz}$ $V_R = 400 \text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1 \text{ MHz}$ $V_R = 800 \text{ V}$, $T_J = 25^\circ\text{C}$, $f = 1 \text{ MHz}$	Fig. 6
E_c	Capacitance Stored Energy	14.5		μJ	$V_R = 800 \text{ V}$	Fig. 7

Note: This is a majority carrier diode, so there is no reverse recovery charge.

Thermal Characteristics

Symbol	Parameter	Typ.	Unit	Note
$R_{\theta JC}$	Thermal Resistance from Junction to Case	0.98	$^\circ\text{C}/\text{W}$	Fig. 9

Typical Performance

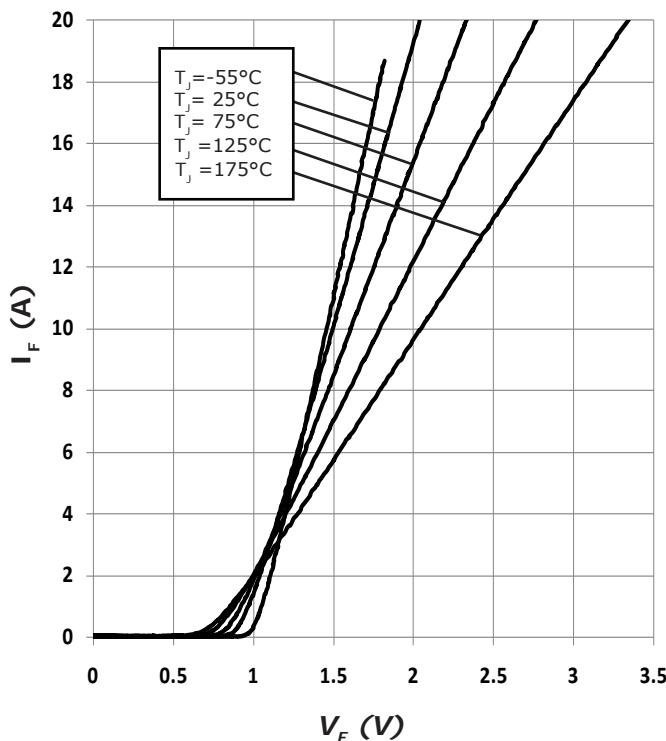


Figure 1. Forward Characteristics

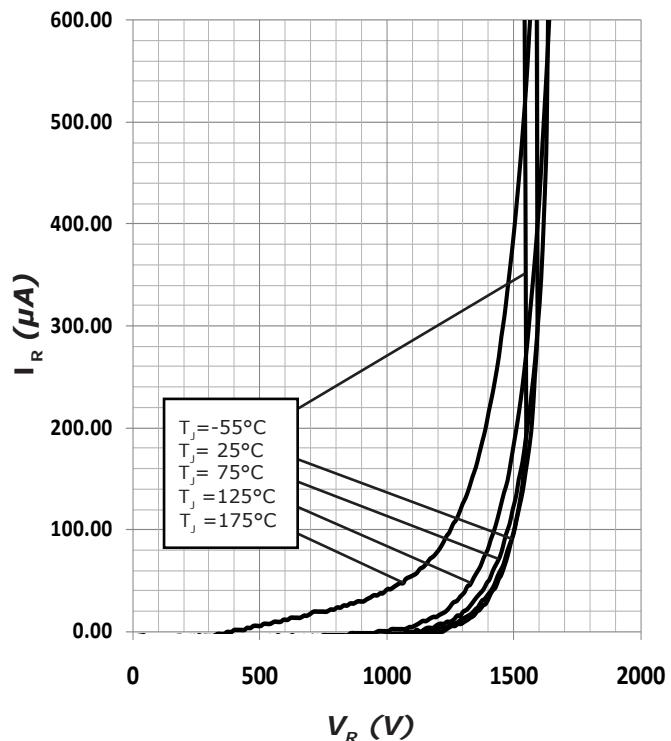


Figure 2. Reverse Characteristics



Typical Performance

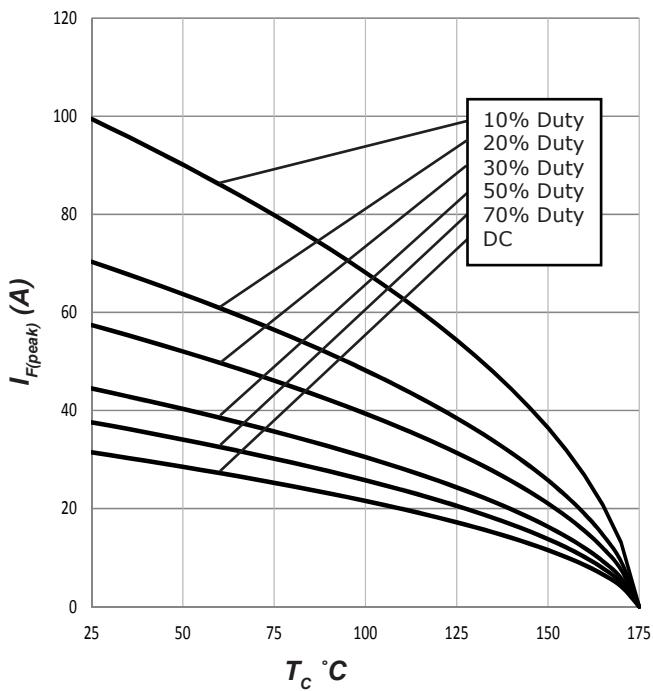


Figure 3. Current Derating

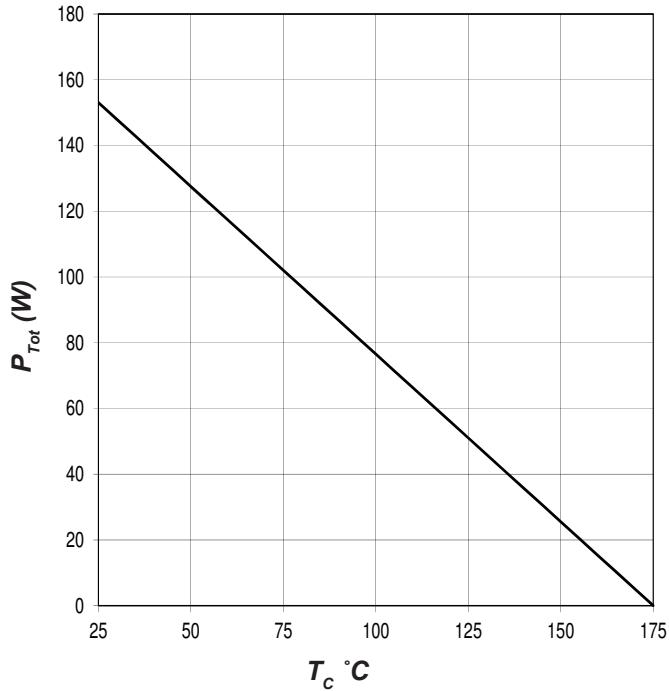


Figure 4. Power Derating

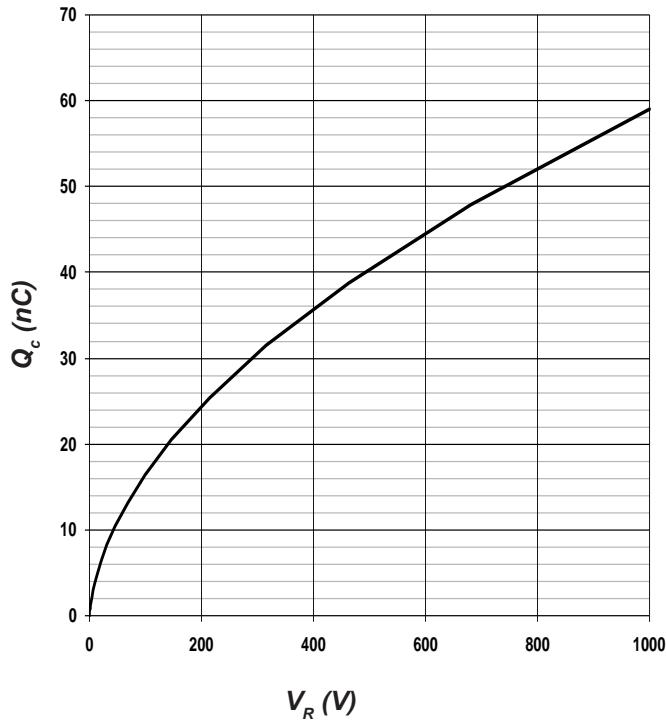


Figure 5. Recovery Charge vs. Reverse Voltage

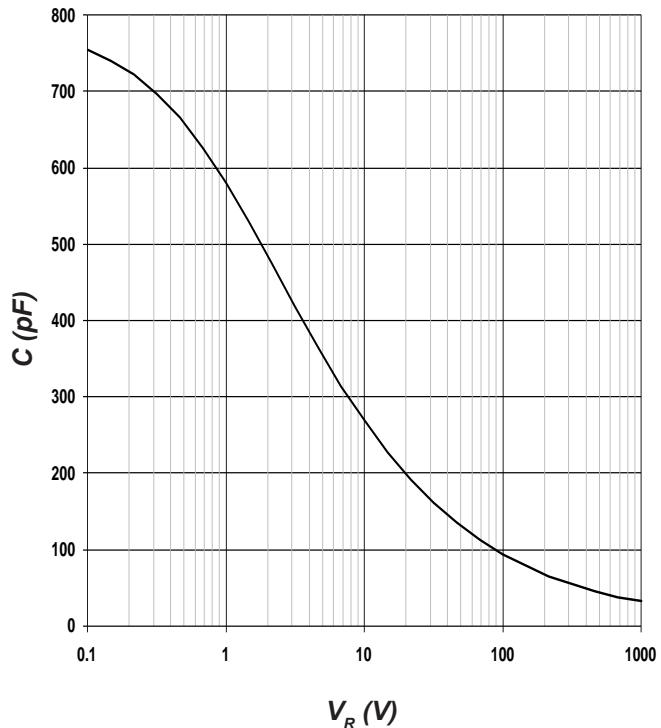


Figure 6. Capacitance vs. Reverse Voltage



Typical Performance

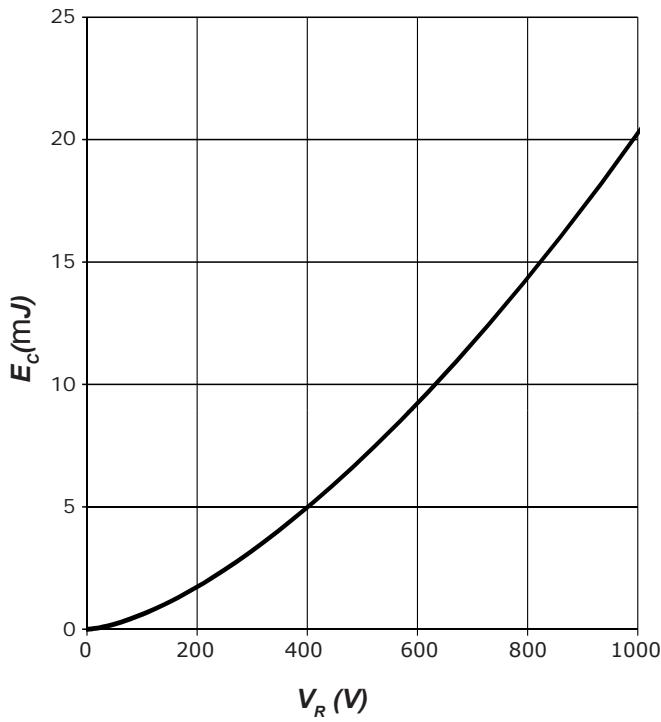


Figure 7. Typical Capacitance Stored Energy

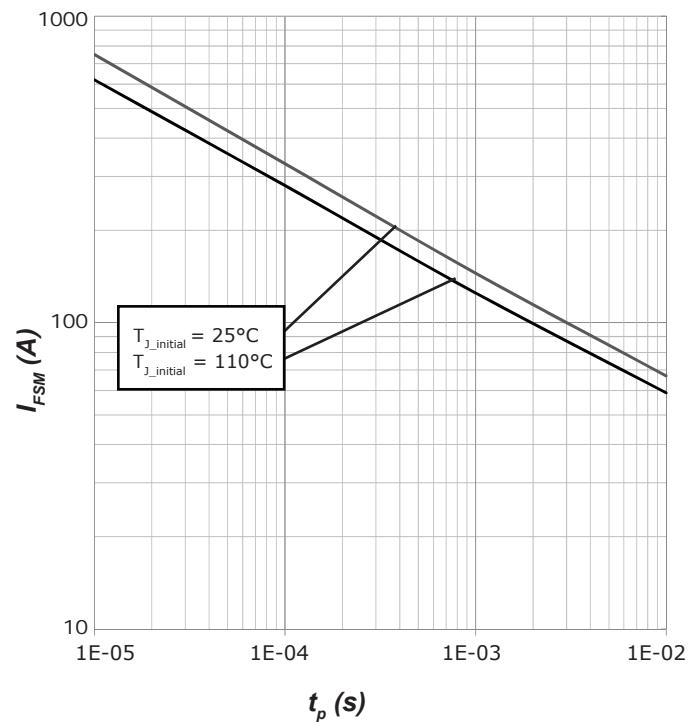


Figure 8. Non-repetitive peak forward surge current versus pulse duration (sinusoidal waveform)

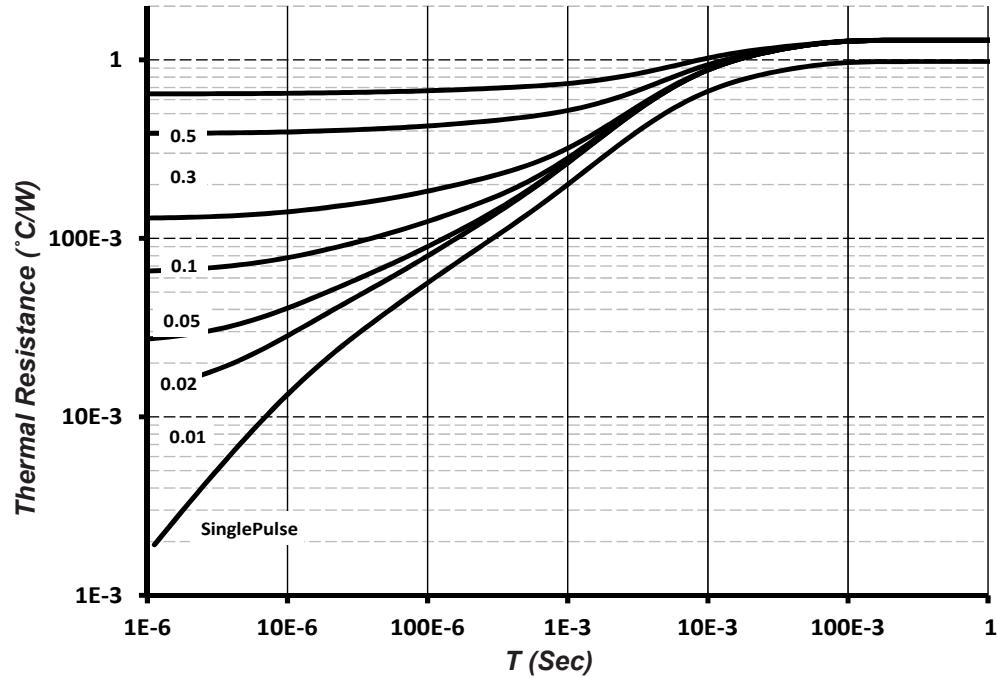
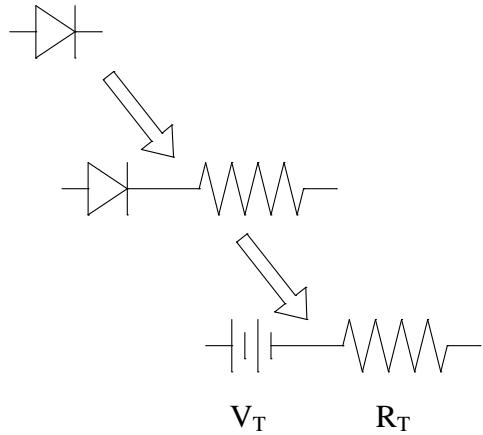


Figure 9. Transient Thermal Impedance



Diode Model



$$V_{fT} = V_T + I_f * R_T$$

$$V_T = 0.98 + (T_J^* - 1.71 * 10^{-3})$$

$$R_T = 0.040 + (T_J^* 5.32 * 10^{-4})$$

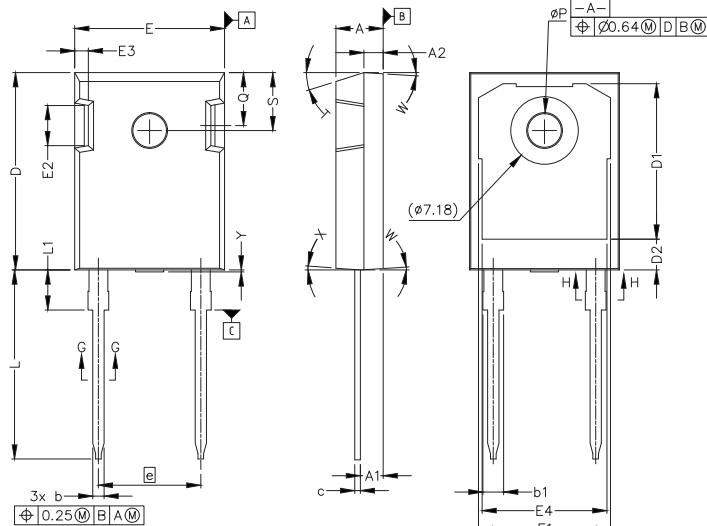
Note: T_J = Diode Junction Temperature In Degrees Celsius,
valid from 25°C to 175°C



Package Dimensions

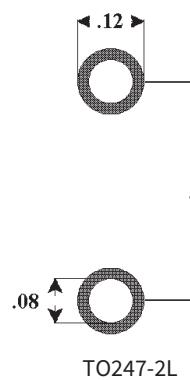
Package: TO247-2L

All dimensions in mm.



SYM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	4.83	5.21	.190	.205
A1	2.29	2.54	.090	.100
A2	1.91	2.16	.075	.085
b'	1.07	1.28	.042	.050
b	1.07	1.33	.042	.052
b1	1.91	2.41	.075	.095
b2	1.91	2.16	.075	.085
c'	0.55	0.65	.022	.026
c	0.55	0.68	.022	.027
D	20.80	21.10	.819	.831
D1	16.25	17.35	.640	.683
D2	2.86	3.16	.112	.124
E	15.75	16.13	.620	.635
E1	13.10	14.15	.516	.557
E2	3.68	5.10	.145	.201
E3	1.00	1.90	.039	.075
E4	12.38	13.43	.487	.529
e	10.88	BSC	.428	BSC
L	19.81	20.32	.780	.800
L1	4.10	4.40	.161	.173
ϕP	3.51	3.65	.138	.144
Q	5.49	6.00	.216	.236
S	6.04	6.30	.238	.248
T	17.5° REF.			
W	3.5° REF.			
X	4° REF.			
Y	0	0.50	0	0.020

Recommended Solder Pad Layout



TO247-2L

all units are in inches



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